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# Maximum Power Dissipation Rating:

500.0 milliwatts

# **Operating Tempurature Range:**

-0.0/+75.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# Features Provided:

Hermetically sealed and monolithic and programmable and 3-state output and w/enable

# Inclosure Material:

Ceramic

# Inclosure Configuration:

Dual-in-line

# Output Logic Form:

Transistor-transistor logic

# Input Circuit Pattern:

10 input

### **Terminal Surface Treatment:**

Solder

### Voltage Rating And Type Per Characteristic:

5.5 volts power source

### Time Rating Per Chacteristic:

70.00 nanoseconds propagation delay time, low to high level output

### Memory Device Type:

Rom

### **Test Data Document:**

05869-726009-1 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

### Terminal Type And Quantity:

16 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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